

#### Quad 2-Input NAND Gate in bare die form

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#### Description

The 54ACT00 quad 2-input NAND gate is fabricated using an advanced 5V CMOS process combining high speed LSTTL performance with CMOS low power. The device consists of x4 independent 2-input NAND gates performing the Boolean function  $Y = \overline{A \cdot B}$  or  $Y = \overline{A} + \overline{B}$ . Internal circuitry comprises of three stages and includes buffered output for high noise immunity and stability. Inputs are directly compatible with LSTTL outputs. All inputs are protected against ESD and excess voltage transients.

#### Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection+ MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
   + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

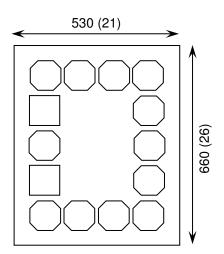
#### Supply Formats:

- Default Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Die Thickness <> 280μm(11 Mils) On request
- Assembled into Ceramic Package On request

#### Features:

- Inputs directly accept TTL
- Outputs directly interface CMOS, NMOS and TTL
- Outputs Source/Sink 24 mA
- Low Input Current: 1μA
- Full Military Temperature Range
- Lower power alternative to bipolar logic
- Functionally compatible with bipolar 54LS00
- Upgrade for 54HCT00.

#### Die Dimensions in μm (mils)



### Mechanical Specification

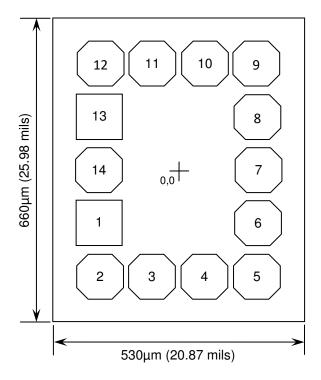
Die Size (Unsawn)	530 x 660 21 x 26	μm mils
Minimum Bond Pad Size	76 x 76 3 x 3	μm mils
Die Thickness	280 (±20) 11.02 (±0.79)	μm mils
Top Metal Composition	Al-Si-Cu	
Back Metal Composition	N/A – Bare S	Si



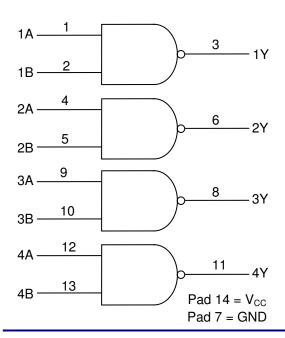


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### Pad Layout and Functions



### Logic Diagram



PAD	FUNCTION	COORDIN	ATES (µm)
PAD	FUNCTION	X	Υ
1	1A	-167	-116
2	1B	-165	-232
3	1Y	-55	-232
4	2A	55	-232
5	2B	165	-232
6	2Y	167	-116
7	GND	168	0
8	3Y	167	116
9	3A	165	232
10	3B	55	232
11	4Y	-55	232
12	4A	-165	232
13	4B	-167	116
14	V <sub>CC</sub>	-168	0
CON	NECT CHIP BA	CK TO V <sub>CC</sub> C	R FLOAT

#### **Function Table**

INP	OUTPUT				
Α	АВ				
L	L	Н			
L	Н	Н			
Н	H L				
Н	H H				
H = High level (steady state) L = Low level (steady state)					





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### Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to GND)	V <sub>CC</sub>	-0.5 to +7.0	V
DC Input Voltage (Referenced to GND)	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> +0.5	V
DC Output Voltage (Referenced to GND)	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> +0.5	V
DC Input Current	I <sub>IN</sub>	±20	mA
DC Output Current, per pad	l <sub>out</sub>	±50	mA
DC Supply Current, V <sub>CC</sub> or GND, per pad	I <sub>CC</sub>	±50	mA
Power Dissipation in Still Air <sup>2</sup>	P <sub>D</sub>	750	mW
Storage Temperature Range	T <sub>STG</sub>	-65 to 150	°C

<sup>1.</sup> Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

## Recommended Operating Conditions<sup>3</sup> (Voltages Referenced to GND)

1 9		` `		
PARAMETER	SYMBOL	MIN	MAX	UNITS
DC Supply Voltage	V <sub>CC</sub>	4.5	5.5	V
DC Input or Output Voltage	V <sub>IN</sub> ,V <sub>OUT</sub>	0	V <sub>CC</sub>	V
Operating Temperature Range	T <sub>J</sub>	-55	+125	°C
Output current - High	I <sub>OH</sub>	-	-24	mA
Output current - Low	I <sub>OL</sub>	-	24	mA
Input Rise or Fall rate V <sub>CC</sub> = 4.5V	Δt/ΔV	0	10	ns/V
$(V_{IN} \text{ from 0.8V to 2V})$ $V_{CC} = 5.5V$	ΔυΔν	0	8	115/ V

<sup>3.</sup> This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{IN}$  and  $V_{OUT}$  should be constrained to the range  $GND \le (V_{IN} \text{ or } V_{OUT}) \le V_{CC}$ . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

#### DC Electrical Characteristics (Voltages referenced to GND)

PARAMETER	SYMBOL	V <sub>CC</sub>	V <sub>CC</sub> CONDITIONS	LIMITS			UNITS
	OTHIDOL	• 66	CONDITIONS	25°C	85°C	FULL RANGE⁴	Olulo
Minimum High-Level	V	4.5V	$V_{OUT} = 0.1V$	2	2	2	V
Input Voltage	V IH	5.5V	or V <sub>CC</sub> -0.1V	2	2	2	V
Maximum Low-Level	V <sub>IL</sub>		$V_{OUT} = 0.1V$	0.8	8.0	0.8	V
Input Voltage	V IL		or V <sub>CC</sub> -0.1V	0.8	8.0	0.8	V
Minimum Low-Level Output Voltage		4.5V	I <sub>OUT</sub> = 50μA	0.1	0.1	0.1	V
		5.5V		0.1	0.1	0.1	
	V	4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^5$	0.36	0.44	0.50	V
	VOL	5.5V	$I_{OL} = 24mA$	0.36	0.44	0.50	V
		4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^{5,6}$	-	-	1.65	V
		5.5V	$I_{OL} = 50 \text{mA}$	-	-	1.65	\ \ \

<sup>4. -55°</sup>C ≤  $T_J$  ≤ +125°C 5. All outputs loaded; thresholds on input associated with output under test. 6. Test time 1sec max, measurement made by forcing indicated current and measuring voltage to minimize power dissipation. Test verifies a minimum 75 $\Omega$  transmission-line drive capability at 125°C





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### DC Electrical Characteristics Continued (Voltages referenced to GND)

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS		LIMI	ΓS	UNITS
	STWIDGE	WIBOL VCC CONDITIONS	25°C	85°C	FULL RANGE⁴	ONTIS	
		4.5V	I <sub>OUT</sub> = 50μA	4.4	4.4	4.4	V
Minimum High-Level	V <sub>OH</sub>	5.5V	1007 = 30μΑ	5.4	5.4	5.4	V
Output Voltage	V OH	4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^5$	3.86	3.76	3.7	V
		5.5V	$I_{OH} = -24mA$	4.86	4.76	4.7	<b>v</b>
Maximum Input Leakage Current	I <sub>IN</sub>	5.5V	$V_{IN} = V_{CC}$ or GND	±0.1	±1.0	±1.0	μΑ
Additional Maximum I <sub>CC</sub> / Input	ΔI <sub>CCT</sub>	5.5V	V <sub>IN</sub> = V <sub>CC</sub> -2.1V	0.6	1.5	1.6	mA
Minimum Dynamic	I <sub>OLD</sub>	5.5V	V <sub>OLD</sub> = 1.65V Max	-	75	50	mA
Output Current <sup>7</sup>	I <sub>OHD</sub>	5.5V	V <sub>OHD</sub> = 3.85V Min	-	-75	-50	IIIA
Maximum Quiescent Supply Leakage Current	I <sub>CC</sub>	5.5V	$\begin{aligned} V_{\text{IN}} &= V_{\text{CC}} \text{ or GND} \\ I_{\text{OUT}} &= 0 \mu A \end{aligned}$	4	40	80	μΑ

<sup>7.</sup> Maximum test duration 2ms, one output loaded at a time.

## AC Electrical Characteristics<sup>8</sup> V<sub>cc</sub> = 5.0V ±0.5V

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS		LIMIT	S	UNITS
1741740121211	7711311121211	• 66	CONDITIONS	25°C	85°C	FULL RANGE⁴	Ottilo
Maximum Propagation Delay	t <sub>PHL</sub>	5.0V	C <sub>L</sub> = 50pF,	7	8	10.8	
Input A or B to Output Y (Figure 1)	t <sub>PLH</sub>	5.0V Input $tr = tf = 3.0ns$	9	9.5	13.2	ns	
Maximum Input Capacitance	C <sub>IN</sub>	5.0V	T <sub>J</sub> = 25°C		<b>TYPIC</b> 2.6	AL	pF
Power Dissipation Capacitance	C <sub>PD</sub>	5.0V	$T_J = 25$ °C, $C_L = 50$ pF	40		pF	

<sup>8.</sup> Not production tested in die form, characterized by chip design and tested in package.





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### Switching Waveform

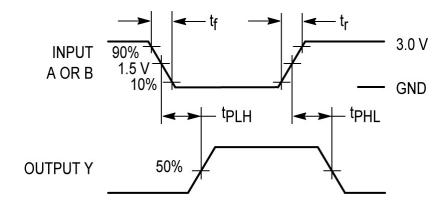
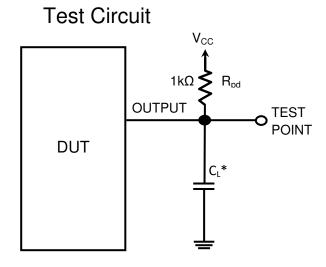


Figure 1 – Propagation delay, Input A or B to Output Y



\* Includes all probe and jig capacitance

Figure 2

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